















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

# **Product Specification**

Domestic Part Number	M1 THRU M7
<ul><li>Overseas Part Number</li></ul>	M1 THRU M7
▶ Equivalent Part Number	M1 THRU M7





## Surface Mount General Purpose Silicon Rectifiers Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

#### **FEATURES**

- For surface mounted applications
- · Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

#### **MECHANICAL DATA**

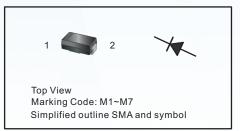
• Case: SMA

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.055g / 0.002oz

#### **PINNING**

PIN	DESCRIPTION		
1	Cathode		
2	Anode		



#### **Maximum Ratings and Electrical characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	M1	M2	М3	M4	M5	M6	М7	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>	1					А		
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I <sub>FSM</sub>	30					А		
Maximum Instantaneous Forward Voltage at 1 A	V <sub>F</sub>	1.1					V		
Maximum DC Reverse Current T <sub>a</sub> = 25 °C at Rated DC Blocking Voltage T <sub>a</sub> = 125 °C	I <sub>R</sub>				5 50				μA
Typical Junction Capacitance (1)	C <sub>j</sub>				15				pF
Typical Thermal Resistance (2)	$R_{\theta JA}$				75				°C/W
Operating and Storage Temperature Range	$T_{j},T_{stg}$			-	55 ~ +15	0			°C

<sup>( 1 )</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C

<sup>(2)</sup> P.C.B. mounted with 1.0 X 1.0" (2.54 X 2.54 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

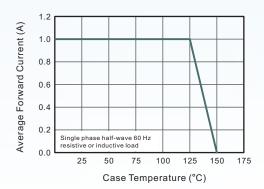


Fig.2 Typical Instaneous Reverse Characteristics

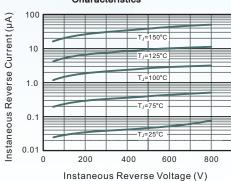


Fig.3 Typical Forward Characteristic

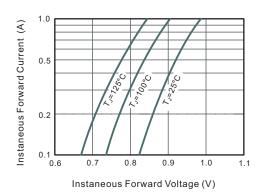


Fig.4 Typical Junction Capacitance

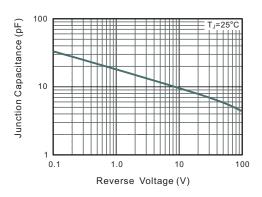
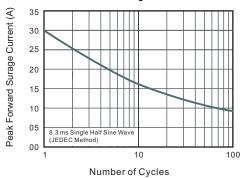


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

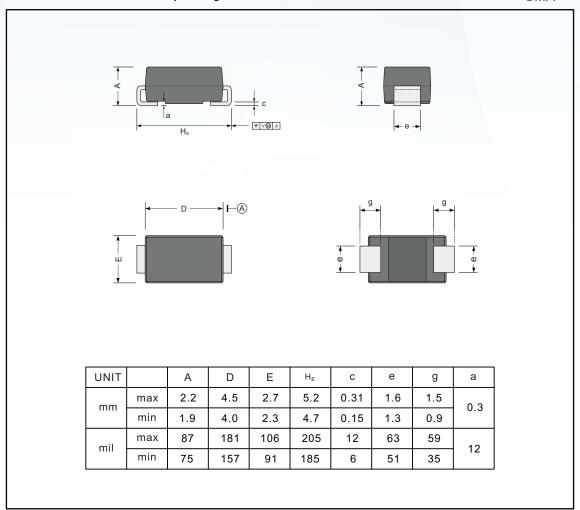




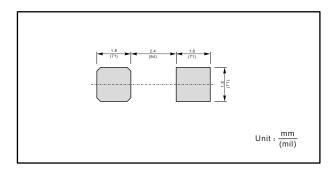
### PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

**SMA** 



#### The recommended mounting pad size



#### Marking

Type number	Marking code				
M1	M1				
M2	M2				
М3	М3				
M4	M4				
M5	M5				
М6	M6				
M7	M7				



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